SM6T Series



Vishay General Semiconductor

Surface Mount TRANSZORB[®] Transient Voltage Suppressors



DO-214AA (SMBJ)

PRIMARY CHARACTERISTICS						
V _{WM}	5.80 V to 188 V					
V _{BR} uni-directional	6.8 V to 220 V					
V _{BR} bi-directional	6.8 V to 220 V					
P _{PPM}	600 W					
PD	5.0 W					
I _{FSM} (uni-directional only)	100 A					
T _J max.	150 °C					
Polarity	Uni-directional, bi-directional					
Package	DO-214AA (SMBJ)					

DEVICES FOR BI-DIRECTION APPLICATIONS

For bi-directional devices use CA suffix (e.g. SM6T12CA). Electrical characteristics apply in both directions.

FEATURES

- Low profile package
- · Ideal for automated placement
- Glass passivated chip junction
- Available in uni-directional and bi-directional
- 600 W peak pulse power capability with a 10/1000 μs waveform
- Excellent clamping capability
- Low inductance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

Use in sensitive electronics protection against voltage transients induced by inductive load switching and lighting on ICs, MOSFET, signal lines of sensor units for consumer, computer, industrial, automotive, and telecommunication.

MECHANICAL DATA

Case: DO-214AA (SMBJ)

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant and commercial grade Base P/NHE3 - RoHS-compliant and AEC-Q101 qualified

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 2 whisker test, HE3 suffix meets JESD 201 class 2 whisker test

Polarity: For uni-directional types the band denotes cathode end, no marking on bi-directional types

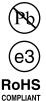
MAXIMUM RATINGS ($T_A = 25 \text{ °C}$ unless otherwise noted)								
PARAMETER	SYMBOL	VALUE	UNIT					
Peak power dissipation with a 10/1000 μs waveform $^{(1)(2)}$ (fig. 1)	P _{PPM}	600	W					
Peak pulse current with a 10/1000 μs waveform $^{(1)}$ (fig. 3)	I _{PPM}	See next table	А					
Power dissipation on infinite heatsink at $T_A = 50 \ ^\circ C$	PD	5.0	W					
Peak forward surge current 10 ms single half sine-wave uni-directional only $^{\left(2\right) }$	I _{FSM}	100	А					
Operating junction and storage temperature range	T _J , T _{STG}	-65 to +150	°C					

Notes

⁽¹⁾ Non-repetitive current pulse, per fig. 3 and derated above $T_A = 25$ °C per fig. 2.

⁽²⁾ Mounted on 0.2" x 0.2" (5.0 mm x 5.0 mm) copper pads to each terminal

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ELECTRICAL CHARACTERISTICS ($T_A = 25$ °C unless otherwise noted)												
TYPE ⁽¹⁾	DEVICE MARKING CODE		BREAKDOWN VOLTAGE V _{BR} AT I _T ⁽²⁾ (V)			STAND-OFF VOLTAGE V _{WM}	LEAKAGE CURRENT I _{RM} AT V _{RM}	CLAMPING VOLTAGE V _C AT Ι _{ΡΡΜ} 10/1000 μs		CLAMPING VOLTAGE V _C AT I _{PP} 8/20 µs		α _T MAX. 10 ⁻⁴ /°C
	UNI	BI	MIN.	MAX.	(mA)	(V)	(μA)	(V)	(A)	(V)	(A)	
SM6T6V8A	KE7	KE7	6.45	7.14	10	5.80	1000	10.5	57.0	13.4	298	5.7
SM6T7V5A	KK7	AK7	7.13	7.88	10	6.40	500	11.3	53.0	14.5	276	6.1
SM6T10A	KT7	AT7	9.50	10.5	1.0	8.55	10.0	14.5	41.0	18.6	215	7.3
SM6T12A	KX7	AX7	11.4	12.6	1.0	10.2	5.0	16.7	36.0	21.7	184	7.8
SM6T15A	LG7	LG7	14.3	15.8	1.0	12.8	1.0	21.2	28.0	27.2	147	8.4
SM6T18A	LM7	BM7	17.1	18.9	1.0	15.3	1.0	25.2	24.0	32.5	123	8.8
SM6T22A	LT7	BT7	20.9	23.1	1.0	18.8	1.0	30.6	20.0	39.3	102	9.2
SM6T24A	LV7	LV7	22.8	25.2	1.0	20.5	1.0	33.2	18.0	42.8	93	9.4
SM6T27A	LX7	BX7	25.7	28.4	1.0	23.1	1.0	37.5	16.0	48.3	83	9.6
SM6T30A	ME7	CE7	28.5	31.5	1.0	25.6	1.0	41.5	14.5	53.5	75	9.7
SM6T33A	MG7	MG7	31.4	34.7	1.0	28.2	1.0	45.7	13.1	59	68	9.8
SM6T36A	MK7	CK7	34.2	37.8	1.0	30.8	1.0	49.9	12.0	64.3	62	9.9
SM6T39A	MM7	CM7	37.1	41.0	1.0	33.3	1.0	53.9	11.1	69.7	57	10.0
SM6T68A	NG7	NG7	64.6	71.4	1.0	58.1	1.0	92.0	6.50	121	33	10.4
SM6T100A	NV7	NV7	95.0	105	1.0	85.5	1.0	137	4.40	178	22.5	10.6
SM6T150A	PK7	PK7	143	158	1.0	128	1.0	207	2.90	265	15	10.8
SM6T200A	PR7	PR7	190	210	1.0	171	1.0	274	2.20	353	11.3	10.8
SM6T220A	PR8	PR8	209	231	1.0	188	1.0	328	2.00	388	10.3	10.8

Notes

(1) For bi-directional devices add suffix "CA"

 $^{(2)}~V_{BR}$ measured after I_{T} applied for 300 μs square wave pulse

⁽³⁾ For bi-polar devices with $V_R = 10$ V or under, the I_T limit is doubled

THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)							
PARAMETER	SYMBOL VALUE		UNIT				
Typical thermal resistance, junction to ambient air (1)	cal thermal resistance, junction to ambient air ⁽¹⁾ R _{0JA} 100						
Typical thermal resistance, junction to lead	$R_{ ext{ heta}JL}$	20	- °C/ W				

Note

⁽¹⁾ Mounted on minimum recommended pad layout

ORDERING INFORMATION (Example)							
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
SM6T10A-E3/52	0.096	52	750	7" diameter plastic tape and reel			
SM6T10A-E3/5B	0.096	5B	3200	13" diameter plastic tape and reel			
SM6T10AHE3/52 (1)	0.096	52	750	7" diameter plastic tape and reel			
SM6T10AHE3/5B (1)	0.096	5B	3200	13" diameter plastic tape and reel			

Note

(1) AEC-Q101 qualified

Revision: 06-Jun-14

2



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RATINGS AND CHARACTERISTICS CURVES ($T_A = 25$ °C unless otherwise noted)

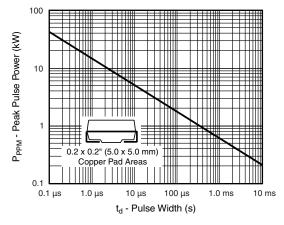


Fig. 1 - Peak Pulse Power Rating Curve

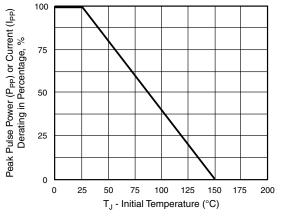


Fig. 2 - Pulse Power or Current vs. Initial Junction Temperature

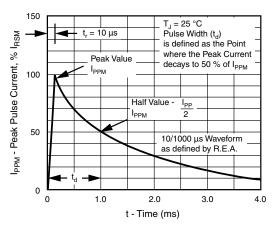


Fig. 3 - Pulse Waveform

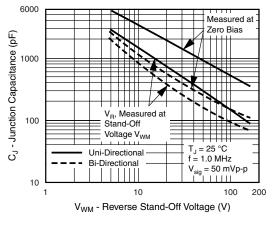


Fig. 4 - Typical Junction Capacitance

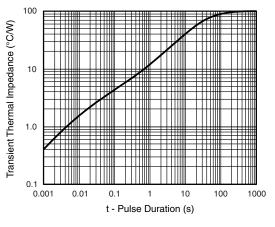


Fig. 5 - Typical Transient Thermal Impedance

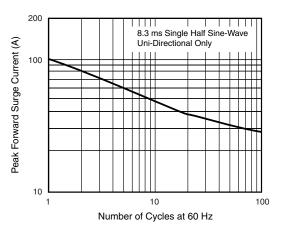


Fig. 6 - Maximum Non-Repetitive Peak Forward Surge Current

Revision: 06-Jun-14

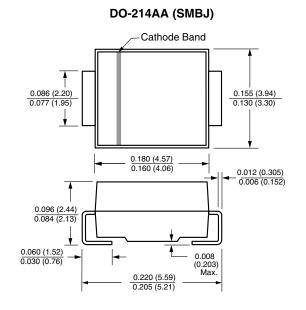
3

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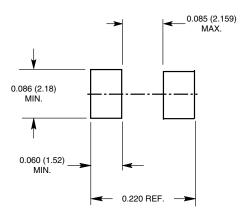


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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



Mounting Pad Layout





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